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PRESIDENCY UNIVERSITY BENGALURU

SCHOOL OF ENGINEERING

MAKEUP EXAMINATION JAN-2023

Course Code: ECE 1001 Date: 28-JAN-2023

Course Name: Elements of Electronics Engineering Time: 09:30AM to 12:30 PM

Programme : B. Tech Max Marks: 100

Weightage: 50%

Instructions:

(i) Read Questions carefully and answer accordingly

(ii) Scientific and Non- programmable calculators are permitted

PART A (Memory Recall Questions)

Answer all the questions. Each question carries SIX Marks.

 $[10Q \times 3M = 30M]$

- 1. The capacitor increases the DC voltage and decreases the ripple voltage components of the output. Therefore, for a half wave rectifier with capacitor filter and full wave filter with capacitor filter the charging time and discharging time are represented by T₁, T₂ respectively. Identify the relation between Charging and discharging time?
 - a. Half wave Rectifier: $T_2 \gg T_1$ and Full Wave Rectifier: $T_2 = T_1$
 - b. Half wave Rectifier: $T_2 = T_1$ and Full Wave Rectifier: $T_2 >> T_1$
 - c. Half wave Rectifier: $T_2 \gg T_1$ and Full Wave Rectifier: $T_1 = T_2/4$
 - d. Half wave Rectifier: $T_2 = T_1/4$ and Full Wave Rectifier: $T_2 >> T_1$
- 2. Efficiency of rectifier is defined as the ratio of output power to the input AC power. The rectifier efficiency determines how effectively the rectifier converts Alternating Current (AC) into Direct Current (DC). Hence, efficiency of full wave rectifier:
 - a)81.2%
 - b)50%
 - c)40.6%
 - d) 45.3%
- 3. Modulation process of varying amplitude of a periodic waveform, called the carrier signal, along with a modulating signal that typically contains information to be transmitted is named as?
 - a) Frequency Modulation

b) Amplitude Modulation

c) Phase Modulation

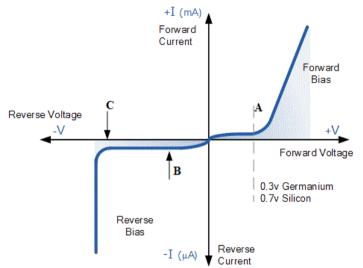
d) All of the above

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	` '			(CO.3) [B. Level: Knowledge]
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on	• •	ne input and only one or		. It is an electronic circuit having te whose output goes High if only
	a) And Gate	b) OR gate c) XO	R gate d) Both a a	nd c
im	ourities added	• .	naterials are class	tor material. Depending upon the ified as N-Type and P-Type aterial?
	(a) Arsenic	(b) Gallium	(c) Boron	(d) Silicon (CO.1) [B. Level: Knowledge]
		controlled Device beca ansistor, the current eq	•	acteristics are determined by the
(a) le=l _B -l _C	(b) IE=IB+IC	(c) I _B =I _E +I _C	(d) Ic=IE+IB
		ctronic circuit having or ates required to realize		e input and only one output. The
		ates required to realize		
nu i) 9. A n	mber of NAND ga 3 b) nicroprocessor is a single integrate	ates required to realize at 2 c) 4 a computer processor w	the AND gate? d) None of the where the data proces	above
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9. A non ha a) b) c)	mber of NAND gate a single integrates 8-bit Data Bus a 8-bit Data Bus a	ates required to realize at 2 c) 4 a computer processor was and 16- address Bus and 8- address Bus and 20- address Bus	the AND gate? d) None of the where the data proces	above (CO.3) [B. Level: Knowledge] ssing logic and control is included
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9. A non ha a) b) d) 10. C	mber of NAND gate 3 b) nicroprocessor is a single integrate s 8-bit Data Bus a 8-bit Data Bus a 16-bit Data Bus None of the about the about the side omplements are simplements are simplements.	ates required to realize at 2 c) 4 a computer processor was and 16- address Bus and 8- address Bus and 20- address Bus ove	the AND gate? d) None of the where the data proces mber of integrated city.	above (CO.3) [B. Level: Knowledge] ssing logic and control is included ircuits. The 8086 microprocessor (CO.4) [B. Level: Knowledge]
9. A non ha a) b) d) 10. C	mber of NAND gate 3 b) nicroprocessor is a single integrate s 8-bit Data Bus at the second	ates required to realize at 2 c) 4 a computer processor was and 16- address Bus and 8- address Bus and 20- address Bus ove used in performing binary of 1000101?	the AND gate? d) None of the where the data proces mber of integrated control of the control of	above (CO.3) [B. Level: Knowledge] ssing logic and control is included ircuits. The 8086 microprocessor (CO.4) [B. Level: Knowledge] metic and logic units. Identify the

PART B (Thought Provoking Questions)

Answer all the Questions. Each Question carries TWENTY Marks. [2Q x 20M = 40M]

11. A diode is a two terminal semiconductor device, P-N junction diode is formed by combining the N-Type and P-Type material together and providing the leads to connect external biasing. The figure below represents PN junction diode characteristics. Refer the figure and answer the following questions:



- In forward bias condition, at point A, value of silicon diode and Germanium diode is 0.7V and 0.3V respectively. Identify and define Point A? (4 M)
- ii. In reverse bias condition, point B represents very low value of current, how the current is measured in reverse bias condition? (4 M)

(a) µ Amperes

- (b) n Amperes
- (c) Amperes
- (d) Both (a) & (b)
- iii. For above PN Junction diode if forward current is given as 3 mA and forward voltage is given as 6 V calculate the static resistance of Diode? (6 M)
- iv. Identify and define Point B and C and also Define and when they occur in PN junction Diode? (6 M)

(CO.1) [B. Level: Comprehension]

12. A microprocessor is a controlling unit of a micro-computer, fabricated on a small chip capable of performing Arithmetic Logical Unit (ALU) operations and communicating with the other devices connected to it. 8085 is an 8-bit microprocessor designed by Intel in 1977 using NMOS technology.

The architecture of 8085 microprocessor provides the idea about what are the operations to be executed and how these are performed like Storing data, executing arithmetic and logic operations and also instructions.

- I) Draw the neat Sketch of 8086 Microprocessor? (10M)
- II) Identify and Differentiate between the General Purpose and Special Purpose registers available in 8086 Microprocessor? (5M)
- III) List some real time applications of Microprocessor? (5M)

(CO.4) [B. Level: Comprehension]

PART C (Problem Solving Questions)

Answer all the Questions. Each Question carries FIFTEEN Marks.

 $[2Q \times 15M = 30M]$

13. a) DeMorgan's Theorem states that inverting the output of any gate results in same function as opposite type of gate (AND vs. OR) with two inverted variables. It is used to solve Boolean Algebra expressions. DeMorgan's first theorem states that two (or more) variables NOR'ed together is the same as the two variables inverted (Complement) and AND'ed, while the second theorem states that two (or more) variables NAND'ed together is the same as the two terms inverted (Complement) and OR'ed. It performs gate operation like NAND gate and NOR gate.

Consider two Boolean Variables A, B and C and verify the two Demorgan's theorems using the truth table?

- i) (A+B+C)' = A'. B. C'
- ii) (ABC)'= A'+ B'+C'
- b) PN-Junction diode is a two terminal semiconductor device that is used for allowing current flow in one direction. They are created by doping or ion implantation process. PN junction diode can be used as a rectifier, logic gate, voltage stabilizer, switching device etc. As BJT is a device in which two PN-diodes are connected back-to-back, which is widely used for amplification purpose in Common Emitter configuration. Henceforth, illustrate the working of a PN-Junction diode in Forward and Reverse Bias Conditions with relevant diagrams. Illustrate with relevant diagrams the Input and Output Characteristics of Common Emitter configuration.

(C.O.No.1) [Comprehension]

- 14. a) Logic gates are the basic building blocks of any digital system. It is an electronic circuit having one or more than one input and only one output. The relationship between the input and the output is based on a certain logic. A universal gate is a gate which can implement any Boolean function without need to use any other gate type. The NAND and NOR gates are universal gates. In practice, this is advantageous since NAND and NOR gates are economical and easier to fabricate and are the basic gates used in all IC digital logic families. If A and B are inputs applied to logic gates and output is denoted with Y then, realize the following expressions using NAND gate?
 - i) Y = A'
 - ii) Y = A*B
 - iii) Y=A+B
 - iv) Y=AB'+ A'B
 - V) Y= A'B'+AB
 - b) A number system is a system representing numbers. It is also called the system of numeration and it defines a set of values to represent a quantity. Perform the following calculations in binary
 - i) $(15)_{10} + (8)_{10}$
 - ii) Convert (1100101010101)2 to Hexadecimal
 - iii) Give the two's complement of (23)₁₀
 - iv) Convert (16)₁₆ to Binary
 - v) If one's complement of a Number is 10101010 find the original number in decimal and also the two's complement of the given one's complement value.

(C.O.NO.3) [B.Level: Comprehension]